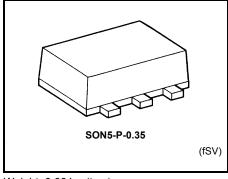
TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7SG125AFS

Bus Buffer with 3-STATE Output

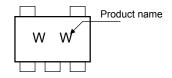
Features

- High-level output current: $I_{OH}/I_{OL} = \pm 8$ mA (min) at $V_{CC} = 3.0$ V
- High-speed operation: t_{pd} = 2.4 ns (typ.) at V_{CC} = 3.3 V,15pF
- Operating voltage range: V_{CC} = 0.9~3.6 V
- 5.5-V tolerant inputs.

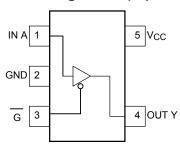


Weight: 0.001 g (typ.)

Marking



Pin Assignment (top view)



Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Value	Unit
Power supply voltage	V _{CC}	-0.5~4.6	V
DC input voltage	V _{IN}	-0.5~7.0	V
DC output voltage	V _{OUT}	-0.5~ V _{CC} + 0.5	V
Input diode current	I _{IK}	-20	mA
Output diode current	lok	±20 (Note 1)	mA
DC output current	lout	±25	mA
DC V _{CC} /ground current	Icc	±50	mA
Power dissipation	P _D	50	mW
Storage temperature	T _{stg}	-65~150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: V_{OUT} < GND, V_{OUT} > V_{CC}

2007-11-01



IEC Logic Symbol



Truth Table

G	Α	Υ
Н	Х	Z
L	L	L
L	Н	Н

Operating Ranges

Characteristics	Symbol	Value	Unit	
Power supply voltage	V _{CC}	0.9~3.6	V	
Input voltage	V _{IN}	0~5.5	V	
Output voltage	V _{OUT}	0~V _{CC}	V	
		±8.0 (Note 2)		
		±4.0 (Note 3)		
Output Current	la/la.	±3.0 (Note 4)	mA	
Output Gurrent	I _{OH} /I _{OL}	±1.7 (Note 5)	IIIA	
		±0.3 (Note 6)		
			±0.02 (Note 7)	
Operating temperature	T _{opr}	-40~85	°C	
Input rise and fall time	dt/dV	0~10 (Note 8)	ns/V	

Note 2: $V_{CC} = 3.0 \sim 3.6 \text{ V}$

Note 3: $V_{CC} = 2.3 \sim 2.7 \text{ V}$

Note 4: $V_{CC} = 1.65 \sim 1.95 \text{ V}$

Note 5: $V_{CC} = 1.4 \sim 1.6 \text{ V}$

Note 6: $V_{CC} = 1.1 \sim 1.3 \text{ V}$

Note 7: $V_{CC} = 0.9 V$

Note 8: $V_{IN} = 0.8 \sim 2.0 \text{ V}, V_{CC} = 3.0 \text{ V}$

Electrical Characteristics

DC Characteristics

Characteristics		0	T4	0		٦	Га = 25°C	;	Ta = -4	0~85°C	1.114	
Ondidotensiles		Symbol	rest	Condition	V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit	
					0.9	V _{CC}	_	_	V _{CC}	_		
					1.1~1.3	V _{CC} × 0.7	_	_	V _{CC} × 0.7			
	High level	VIH			1.4~1.6	V _{CC} × 0.65	_	_	V _{CC} × 0.65	_		
					1.65~ 1.95	V _{CC} × 0.65	ı	ı	V _{CC} × 0.65			
					2.3~2.7	1.7	l	ı	1.7			
Input voltage					3.0~3.6	2.0	_	_	2.0	_	V	
input voltage					0.9	_		GND	_	GND	v	
					1.1~1.3			V _{CC} × 0.3	_	V _{CC} × 0.3		
	Low level	V _{IL}		_	1.4~1.6		l	V _{CC} × 0.35		V _{CC} × 0.35		
					1.65~ 1.95		_	V _{CC} × 0.35	_	V _{CC} × 0.35		
					2.3~2.7	_	_	0.7	_	0.7		
						3.0~3.6	_	_	0.8	_	0.8	
		Voн		I _{OH} =-0.02 mA	0.9	0.75	_	_	0.75	_		
	High level		V _{IN} = V _{IH} or V _{IL} ,	$I_{OH} = -0.3 \text{ mA}$	1.1~1.3	V _{CC} × 0.75	_	_	V _{CC} × 0.75			
				$I_{OH} = -1.7 \text{ mA}$	1.4~1.6	V _{CC} × 0.75	_	_	V _{CC} × 0.75	_		
				$I_{OH} = -3.0 \text{ mA}$	1.65~ 1.95	V _{CC} -0.45	_	_	V _{CC} -0.45	_		
				$I_{OH} = -4.0 \text{ mA}$	2.3~2.7	2.0	_	_	2.0	_		
Output voltage				$I_{OH} = -8.0 \text{ mA}$	3.0~3.6	2.48	_	_	2.48	_	V	
Output voltage	ge			$I_{OL} = 0.02 \text{ mA}$	0.9	_	_	0.1	_	0.1	V	
				I _{OL} = 0.3 mA	1.1~1.3			V _{CC} × 0.25	_	V _{CC} × 0.25		
	Low level	V _{OL}	$V_{IN} = V_{IL}$	I _{OL} = 1.7 mA	1.4~1.6		_	V _{CC} × 0.25	_	V _{CC} × 0.25		
				I _{OL} = 3.0 mA	1.65~ 1.95		_	0.45	_	0.45		
				I _{OL} = 4.0 mA	2.3~2.7	_	_	0.4	_	0.4		
				I _{OL} = 8.0 mA	3.0~3.6	_		0.4	_	0.4		
Input leakage curre	ent	I _{IN}	V _{IN} = 0~5.	.5V	0~3.6	_		±0.1	_	±1.0	μΑ	
3-state output off-s current	tate	loz	$V_{IN} = V_{IH}$ $V_{OUT} = 0$	or V _{IL} , ~3.6 V	0.9~3.6	_	_	1.0	_	10.0	μА	
Quiescent supply of	current	Icc	$V_{IN} = V_{CC}$	or GND	3.6	_		1.0	_	10.0	μΑ	



AC Characteristics (Input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Cumbal	Test Condition		-	Га = 25°C		Ta = -4	Ta = -40~85°C	
Characteristics	Symbol	rest Condition	V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
			0.9 — 15.3		_	_	_		
			1.1~1.3		8.3	18.4	1.0	34.2	
		C _L = 10 pF,	1.4~1.6	_	5.0	8.5	1.0	10.0	
		$R_L = 1 M\Omega$	1.65~ 1.95	_	4.0	6.2	1.0	6.7	
			2.3~2.7	_	2.6	3.9	1.0	4.4	
			3.0~3.6	_	2.1	3.1	1.0	3.7	
			0.9		17.7	_	_	_	
			1.1~1.3		9.6	21.5	1.0	37.2	
Dronovation delevations	t _{pLH}	C _L = 15 pF,	1.4~1.6		5.6	9.3	1.0	11.2	
Propagation delay time	t _{pHL}	$R_L = 1 M\Omega$	1.65~ 1.95		4.5	6.9	1.0	7.1	ns
			2.3~2.7		2.9	4.4	1.0	5.0	
			3.0~3.6		2.4	3.4	1.0	3.9	
		C _L = 30 pF,	0.9		29.0	_	_	_	
			1.1~1.3	_	14.5	29.6	1.0	56.0	
			1.4~1.6		8.2	13.1	1.0	15.9	
		$R_L = 1 M\Omega$	1.65~ 1.95		6.0	6.0 9.2	1.0	9.6	
			2.3~2.7	_	4.0	5.7	1.0	6.1	
			3.0~3.6		3.3	4.4	1.0	4.8	
		$C_L = 10 \text{ pF},$ $R_L = 100 \text{ k}\Omega$	0.9	_	18.9	_	_	_	ns
			1.1~1.3	_	9.8	16.9	1.0	24.8	
			1.4~1.6	_	5.3	7.8	1.0	8.3	
		$C_L = 10 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	1.65~ 1.95	_	3.9	5.5	1.0	5.9	
			2.3~2.7		2.5	3.5	1.0	3.8	
			3.0~3.6	_	2.1	2.7	1.0	3.0	
		$C_L = 15 \text{ pF},$ $R_L = 100 \text{ k}\Omega$	0.9	_	22.0	_	_	_	
			1.1~1.3	_	11.0	18.7	1.0	28.4	
Output enable time	t _{pZL}		1.4~1.6		5.9	8.9	1.0	11.0	
	t _{pZH}	$C_L = 15 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	1.65~ 1.95	_	4.4	6.3	1.0	6.5	
		0 1/32	2.3~2.7		2.9	3.9	1.0	4.2	
			3.0~3.6		2.3	3.0	1.0	3.3	
		$C_L = 30 \text{ pF},$ $R_L = 100 \text{ k}\Omega$	0.9	_	31.8	_	_	_	
			1.1~1.3	_	15.6	27.3	1.0	43.2	
			1.4~1.6	_	8.3	12.2	1.0	13.7	
		$C_L = 30 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	1.65~ 1.95		6.1	8.6	1.0	9.7	
			2.3~2.7	_	3.8	5.0	1.0	5.5	
			3.0~3.6	_	2.9	3.8	1.0	4.2	

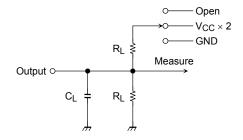
Characteristics Symbol Tes		Test Condition		-	Ta = 25°C		Ta = -40~85°C		Unit		
Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Тур.	Max	Min	Max	Offic		
		$\begin{aligned} C_L &= 10 \text{ pF}, \\ R_L &= 100 \text{ k}\Omega \end{aligned}$	0.9	_	100.4	_	_	_			
			1.1~1.3		9.1	14.4	1.0	22.4			
			1.4~1.6		7.1	9.1	1.0	10.4			
		$C_L = 10 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	1.65~ 1.95		6.5	8.3	1.0	9.0			
		_	2.3~2.7	_	5.8	7.3	1.0	8.8			
			3.0~3.6		5.4	6.9	1.0	7.6			
	t _P LZ t _P HZ	$\begin{aligned} C_L &= 15 \text{ pF}, \\ R_L &= 100 \text{ k}\Omega \end{aligned}$	0.9	_	122.2	_	_	_			
Output disable time			1.1~1.3		9.8	15.3	1.0	25.1	ns		
			1.4~1.6	_	7.8	9.8	1.0	11.3			
					1.65~ 1.95		7.2	9.2	1.0	10.6	
					2.3~2.7		7.0	8.2	1.0	10.3	
			3.0~3.6	_	6.6	7.7	1.0	9.5			
		$\begin{aligned} C_L &= 30 \text{ pF}, \\ R_L &= 100 \text{ k}\Omega \end{aligned}$	0.9	_	217.1	_	_	_			
			1.1~1.3	_	13.2	19.6	1.0	31.9			
			1.4~1.6	_	12.2	13.5	1.0	14.9			
		$C_L = 30 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	1.65~ 1.95	_	11.4	12.7	1.0	13.9			
		_	2.3~2.7		11.3	12.2	1.0	13.5			
			3.0~3.6		10.2	11.5	1.0	12.9			
Input capacitance	C _{IN}	_	3.6		3		_	_	pF		
Power dissipation capacitance	C _{PD}	(Note 9)	0.9 ~ 3.6	_	6	_	_	_	pF		

Note 9:C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC \text{ (opr.)}} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

AC Characteristics Measurement Circuit



Characteristics	Switch
t _{pLH} , t _{pHL}	Open
t _{pLZ,} t _{pZL}	V _{CC} × 2
t _{pHZ,} t _{pZH}	GND

Figure1 tpLH, tpHL

AC Characteristics Measurement Circuit

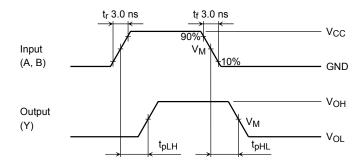
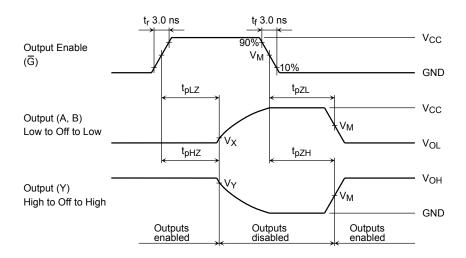


Figure 2 tpLH, tpHL

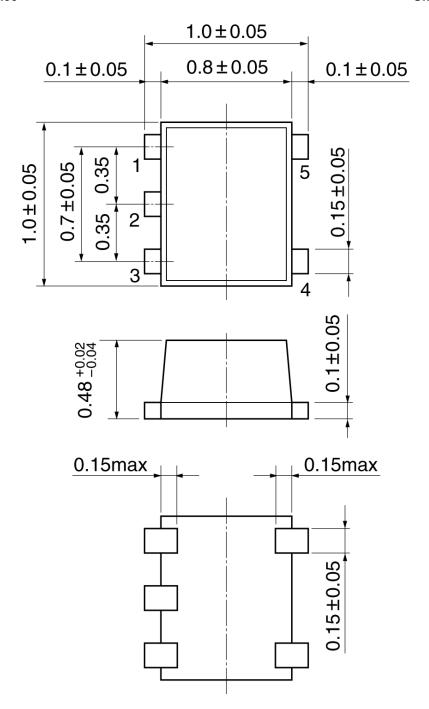


 $\textbf{Figure3} \quad t_{pLZ},\, t_{pHZ},\, t_{pZL},\, t_{pZH}$

UNIT	Vcc								
ONIT	3.3±0.3 V	2.5±0.2 V	1.8±0.15 V	1.5±0.1 V	1.2±0.1 V	0.9 V			
V_{M}	V _{CC} / 2	V _{CC} / 2	V _{CC} / 2	V _{CC} / 2	V _{CC} / 2	V _{CC} / 2			
VX	V _{OL} + 0.3 V	V _{OL} + 0.15 V	V _{OL} + 0.15 V	V _{OL} + 0.1 V	V _{OL} + 0.1 V	V _{OL} + 0.1 V			
VY	V _{OH} - 0.3 V	V _{OH} - 0.15 V	V _{OH} - 0.15 V	V _{OH} - 0.1 V	V _{OH} - 0.1 V	V _{OH} - 0.1 V			

Package Dimensions

SON5-P-0.35 Unit:mm



Weight: 0.001 g (typ.)

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20070701-EN GENERAL

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